NSN 5961-00-558-7933

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-558-7933

| Internal Configuration: |
|---|
| Junction contact |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 40.0 breakdown voltage, collector-to-emitter, base |
| open and 5.0 breakdown voltage, emitter-to-base, collector open |
| Current Rating Per Characteristic: |
| 50.00 microamperes zero-gate-voltage source current preset |
| Transfer Ratio: |
| 20.0 static forward current transfer ratio, common-emitter |
| Special Features: |
| Junction pattern arrangement: npn |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| - |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |